

3D Diamond Development for tracking and dosimetry measurements

lain Haughton, PhD The University of Manchester iain.haughton@cern.ch



Authors

[1] The University of Manchester – Manchester, UK Alex Oh, Iain Haughton, Steve Murphy, Giulio Forcolin, Francisca Munoz Sanchez, Olivier Allegre, David Whitehead

> [2] The University of Oxford – Oxford, UK Martin Booth, Patrick Salter

[3] Ruder Boskovic Institute – Zagreb, Croatia Milko Jaksic, Natko Skukan



Introduction – why 3D?



Build an ultra radiation tolerant particle detector. Improve the performance of polycrystalline diamond for high precision particle detectors.



• Carriers have to travel a much shorter distance in 3D to get equivalent charge induced.

Number of carriers

$$h(t) = n_0 e^{-t/\tau}$$

Carrier lifetime

- τ decreases with radiation exposure.
- τ is smaller in polycrystalline diamond than in single crystal diamond.



Introduction - applications

• High energy physics:





• Medical dosimetry (proton therapy):







Fabrication

The University of Manchester – Manchester, UK

The University of Oxford – Oxford, UK

[4] M. Booth et al, "Three dimensional laser micro fabrication in diamond a using dual adaptive optics system", Opt. Express (2011).

[5] M. Booth and A. Jesacher, "Parallel direct laser writing in three dimensions with spatially dependent aberration correction", Opt. Express (2010).



Column formation - laser processing







- Laser wavelength = 800nm.
- Laser pulse length = 120fs.
- Transform sp³ diamond (non conductive material) into a combination of diamond-like carbon, amorphous carbon and graphite (conductive material).







































Objective lens

Numerical Aperture (NA):

• Higher NA \rightarrow Increased focal resolution.



[6] Kroto Imaging Facility, The University of Sheffield.



Light aberration





The University of Manchester





The University of Manchester



[7] F.Bachmair et al., NIMA 786 (2015) 97-104



Spatial Light Modulator (SLM) correction

Phase shift/ π





Laser setup





Laser setup – Manchester











[4], [5]





		Translation speed			
		5um/s	10um/s	20um/s	30um/s
Beam energy	100nJ	х	х		
	200nJ	х	х	Х	
	300nJ		Х	Х	Х
	400nJ		Х	Х	Х
	500nJ			Х	Х
	600nJ				X

• Repeat with and without SLM.



X polarisers



• Optical grade single crystal diamond.



X polarisers



• Post processing.







Surface measurement





Surface measurement





Raman – with SLM



Exit surface exhibits a higher ratio than the seed:
 → Possibly due to ejection of material.

30



Raman – without SLM



Seed surface exhibits a much higher ratio than the exit:
 → Light aberration is maximum at the seed surface.



Internal structure



[5] K.K. Ashikkalieva et al., Carbon 102 (2016) 383-389





X polarisers

Metallisation in Manchester:

- Chromium
- Gold

Seed surface structured. Exit surface pad.

Metallisation





IV curves

• Ohmic and barrier potential curves observed.





Barrier potential









36



With SLM





With SLM





The University of Mancheste

Resistance



- Decreases as a power law \rightarrow multi-photon absorption.
- Clear discrepancy at 30um/s.



Raman – with SLM



No discrepancy seen in Raman at 30um/s.
 → Surface measurement.



Barrier energy





Multiple passes



Multiple passes reduces resistance and increases uniformity of the columns.



Multiple passes





The University of Manchester

Lens NA



 \rightarrow Reduced resistance at 200nJ.









Summary

The method of column production has been vastly improved using an SLM.

 \rightarrow However, high column resistivity is still a problem.

I've shown preliminary results for a comprehensive study of drilling parameters, including the measurement of:

- Surface diamond:graphite ratios.
- Morphology.
- IV characteristics.
- SLM is key to maintain the effective lens NA with depth.
- Higher NA \rightarrow higher focal resolution \rightarrow lower column resistivity.
- Speed needs to be tuned in order to minimise barrier potential.

Resistivity can be reduced further, but it takes much longer to form columns.

Future \rightarrow lower resistivity in manageable timescales.



Thank you



Back up



Property (relative to silicon)	Silicon	Diamond
Energy gap	1	5 (3.5 <i>e-h</i> creation)
Dielectric constant	1	0.5
Thermal conductivity	1	13.5
Thermal expansion coefficient	1	0.03
Electron mobility	1	3.0
Hole mobility	1	6.3
Displacement energy	1	1.4



Introduction – types of diamond



Single Crystal

- Very good carrier properties.
- Small areas available.

Polycrystalline



- Reduced mean free path of carriers.
- Large areas available.





$$\Delta \phi = n_2 l_2 - n_1 l_1$$

- Apply Snell's law.
- Assume lens obeys sine condition.

$$\Delta \phi(r) = -\frac{2\pi d}{\lambda_0 f} \left[\sqrt{f^2 n_2^2 - r^2} - \sqrt{f^2 n_1^2 - r^2} \right]$$

[5], [6]









• Integrate around the optical axis.

















The University of Manchester

Current (I) versus applied bias voltage ($U_{\rm b}$) measurement:

- *Keithley* 2410 source meter.
- Exit surface grounded.
- Seed surface probed.





Transient current signals at 20V



The University of Manchester



Charge production at depth

The University of Manchester





Depth (µm)

Column resistance



60

Entries [a.u.]



Sample flipping



61